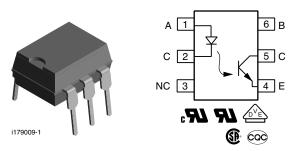


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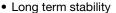
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## **Optocoupler, Phototransistor Output, no Base Connection**



### **FEATURES**

- Isolation test voltage, 5300 V<sub>RMS</sub>
- No base terminal connection for improved common mode interface immunity



- Industry standard dual in line package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





RoHS

#### **LINKS TO ADDITIONAL RESOURCES**













### **DESCRIPTION**

The MOC8101, MOC8102, MOC8103, MOC8104 family optocoupler consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon planar phototransistor detector in a plastic plug-in DIP-6 package.

The coupling device is suitable for signal transmission between two electrically separated circuits. The potential difference between the circuits to be coupled should not exceed the maximum permissible reference voltages.

The base terminal of the MOC8101, MOC8102, MOC8103, MOC8104 is not connected, resulting in a substantially improved common mode interference immunity.

### **AGENCY APPROVALS**

- UL
- cUL
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- BSI EN 62368-1
- CQC GB4943.1-2011
- CQC GB8898-2011
- CSA

#### **ORDERING INFORMATION** Option 6 М 0 С 8 1 0 # Χ 0 # Т PART NUMBER **CTR** PACKAGE OPTION TAPE 10.16 mr RIN AND Option 7 Option 9 REEL **CTR (%) AGENCY CERTIFIED / PACKAGE** 10 mA **UL, CSA, BSI** 73 to 117 108 to 173 160 to 256 50 to 80 DIP-6 MOC8102 MOC8103 MOC8104 MOC8101 DIP-6, 400 mil, option 6 MOC8102-X006 MOC8102-X009 SMD-6, option 9 VDE, UL, CSA, BSI 73 to 117 108 to 173 160 to 256 50 to 80 MOC8103-X001 DIP-6 DIP-6, 400 mil MOC8102-X016 MOC8104-X016 MOC8102-X017T (1) MOC8101-X017T SMD-6, option 7 MOC8104-X019T SMD-6, option 9

#### Notes

- · Additional options may be possible, please contact sales office
- (1) Also available in tubes; do not put T on end

## MOC8101, MOC8102, MOC8103, MOC8104

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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		$V_{R}$	6.0	V		
Forward continuous current		I <sub>F</sub>	60	mA		
Surge forward current	t ≤ 10 µs	I <sub>FSM</sub>	2.5	Α		
Power dissipation		P <sub>diss</sub>	100	mW		
Derate linearly from 25°C			1.33	mW/°C		
OUTPUT						
Collector emitter breakdown voltage		BV <sub>CEO</sub>	30	V		
Emitter collector breakdown voltage		BV <sub>ECO</sub>	7.0	V		
Collector current		Ic	50	mA		
Derate linearly from 25°C			2.0	mW/°C		
Power dissipation		P <sub>diss</sub>	150	mW		
COUPLER						
Derate linearly from 25 °C			3.33	mW/°C		
Total power dissipation		P <sub>tot</sub>	250	mW		
Storage temperature		T <sub>stg</sub>	-55 to +150	°C		
Operating temperature		T <sub>amb</sub>	-55 to +100	°C		
Junction temperature		Tj	100	°C		
Soldering temperature (1)	max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C		

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP)

ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 10 \text{ mA}$		$V_{F}$	-	1.25	1.5	V
Breakdown voltage	$I_R = 10 \mu A$		$V_{BR}$	6.0	-	-	V
Reverse current	V <sub>R</sub> = 6.0 V		I <sub>R</sub>	-	0.01	10	μA
Capacitance	$V_R = 0 V, f = 1.0 MHz$		Co	-	25	-	pF
Thermal resistance			R <sub>thja</sub>	-	750	-	K/W
OUTPUT							
Collector emitter capacitance	V <sub>CE</sub> = 5.0 V, f = 1.0 MHz		C <sub>CE</sub>	-	5.2	-	pF
	V <sub>CE</sub> = 10 V, T <sub>amp</sub> = 25 °C	MOC8101	I <sub>CEO1</sub>	-	1.0	50	nA
Collector emitter dark current	V <sub>CE</sub> = 10 V, T <sub>amp</sub> = 100 °C	MOC8102	I <sub>CEO1</sub>	-	1.0	-	μA
Collector emitter breakdown voltage	I <sub>C</sub> = 1.0 mA		BV <sub>CEO</sub>	30	-	-	V
Emitter collector breakdown voltage	I <sub>E</sub> = 100 μA		BV <sub>ECO</sub>	7.0	-	-	V
Thermal resistance			R <sub>thja</sub>	-	500	-	K/W
COUPLER							
Saturation voltage collector emitter	I <sub>F</sub> = 5.0 mA		V <sub>CEsat</sub>	-	0.25	0.4	V
Coupling capacitance			C <sub>C</sub>	_	0.6	_	рF

#### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements



# MOC8101, MOC8102, MOC8103, MOC8104

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CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	V <sub>CE</sub> = 10 V, I <sub>F</sub> = 10 mA	MOC8101	CTR	50	-	80	%
		MOC8102	CTR	73	-	117	%
		MOC8103	CTR	108	-	173	%
		MOC8104	CTR	160	-	256	%

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$V_{CC} = 10 \text{ V}, I_{C} = 2.0 \text{ mA}, R_{L} = 100 \Omega$	t <sub>on</sub>	-	3.0	-	μs
Turn-off time	$V_{CC} = 10 \text{ V}, I_{C} = 2.0 \text{ mA}, R_{L} = 100 \Omega$	t <sub>off</sub>	-	2.3	-	μs
Rise time	$V_{CC} = 10 \text{ V}, I_{C} = 2.0 \text{ mA}, R_{L} = 100 \Omega$	t <sub>r</sub>	-	2.0	-	μs
Fall time	$V_{CC}$ = 10 V, $I_{C}$ = 2.0 mA, $R_{L}$ = 100 $\Omega$	t <sub>f</sub>	-	2.0	-	μs
Cut off frequency		f <sub>co</sub>	-	250	-	kHz

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification	According to IEC 68 part 1		55 / 100 / 21			
Comparative tracking index		CTI	175			
Maximum rated withstanding isolation voltage	t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>		
Maximum transient isolation voltage		V <sub>IOTM</sub>	10 000	V		
Maximum repetitive peak isolation voltage		V <sub>IORM</sub>	890	V		
In elektron westekenne	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω		
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω		
Output safety power		P <sub>SO</sub>	400	mW		
Input safety current		I <sub>SI</sub>	275	mA		
Input safety temperature		T <sub>SI</sub>	175	°C		
Creepage distance	Standard DIP-6		≥ 7	mm		
Clearance distance	Standard DIP-6		≥ 7	mm		
Creepage distance	400 mil DIP-6		≥ 8	mm		
Clearance distance	400 mil DIP-6		≥ 8	mm		
Insulation thickness		DTI	≥ 0.4	mm		

### Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits

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### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

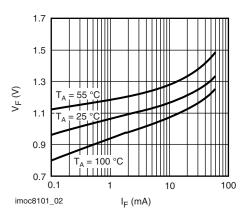


Fig. 1 - Forward Voltage vs. Forward Current

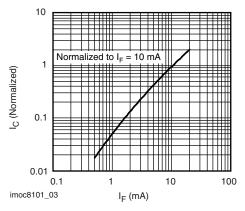


Fig. 2 - Collector Current vs. LED Forward Current

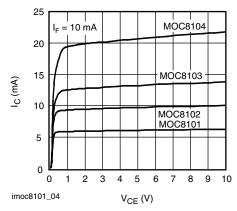


Fig. 3 - Collector Current vs. Collector Emitter Voltage

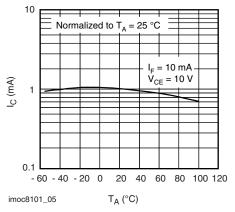


Fig. 4 - Collector Current vs. Ambient Temperature

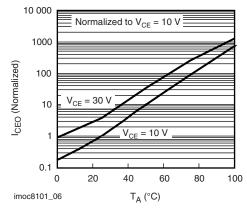


Fig. 5 - Collector Emitter Dark Current vs. Ambient Temperature

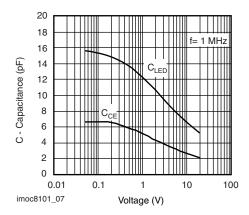


Fig. 6 - Capacitance vs. Voltage

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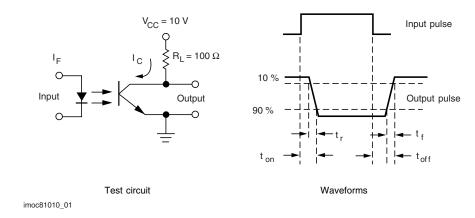
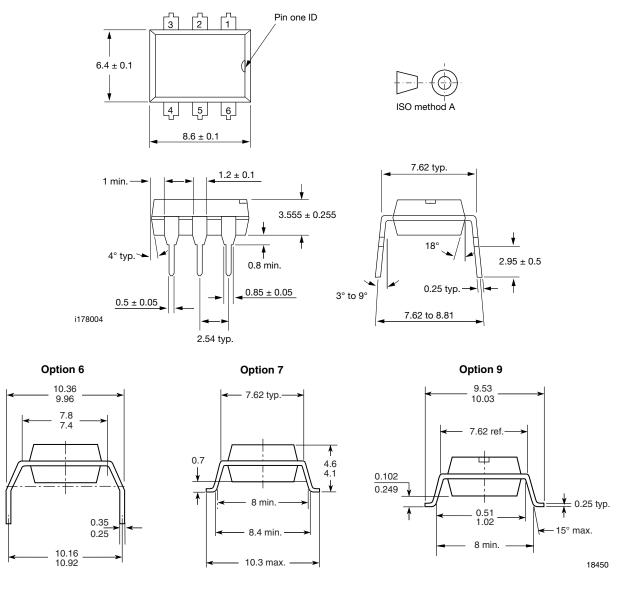


Fig. 7 - Switching Time Test Circuit and Waveforms

### **PACKAGE DIMENSIONS** in millimeters





## **Legal Disclaimer Notice**

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